ART2K0TFE; ART2K0TFES; ART2K0TFEG Power LDMOS transistor Rev. 3 – 12 February 2025 Product of

AMPLEON Product data sheet

Product profile 1.

1.1 General description

Based on Advanced Rugged Technology (ART), this 2000 W LDMOS RF power transistor has been designed to cover a wide range of applications for ISM, broadcast and communications. The unmatched transistor has a frequency range of 1 MHz to 400 MHz.

Table 1. **Application information**

Test signal	f	V _{DS}	PL	G _p	η D
	(MHz)	(V)	(W)	(dB)	(%)
CW pulsed [1]	108	65	2000	29.1	73.3

[1] Test circuit: $t_p = 100 \ \mu s; \ \delta = 10 \ \%$.

1.2 Features and benefits

- High breakdown voltage enables class E operation up to V_{DS} = 53 V
- Qualified up to a maximum of V_{DS} = 65 V
- Characterized from 30 V to 65 V to support a wide range of applications
- Integrated thermal sensor
- Integrated dual sided ESD protection enables class C operation and complete switch off of the transistor
- Excellent ruggedness with no device degradation
- High efficiency
- Excellent thermal stability
- Designed for broadband operation
- For RoHS compliance see the product details on the Ampleon website

1.3 Applications

- Industrial, scientific and medical applications
 - Plasma generators
 - MRI systems
 - CO₂ lasers
 - Particle accelerators
- Broadcast
 - FM radio
 - VHF TV
- Communications
 - Non cellular communications
 - UHF radar

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2. Pinning information

Pin	Description	Simplified outline	Graphic symbol
ART	2K0TFE (ACC-1230-6F-3)		
1	drain1		4
2	drain2		
3	gate1		
4	gate2		
5	source		
6	temperature sense FET1	[2] 6 3 4 7	
7	temperature sense FET2	[2]	2 7 emp01794
ART	2K0TFES (ACC-1230-6F-2)		
1	drain1		4
2	drain2		
3	gate1		
4	gate2		5
5	source		
6	temperature sense FET1	[2] 6 3 4 7	
7	temperature sense FET2	[2]	2 7 amp01794
ART	2K0TFEG (ACC-1230-6G-2)		
1	drain1		
2	drain2	1 2	
3	gate1		
4	gate2		5
5	source		
6	temperature sense FET1	[<u>2]</u> 6 3 4 7	
7	temperature sense FET2	[2]	2 7 amp01794

- [1] Connected to flange.
- [2] The ART2K0TFE, ART2K0TFES and ART2K0TFEG are equipped with a thermal sense FET and can be used to sense the die temperature during operation of the device. This thermal FET is electrically disconnected from the RF power FETs on the die and share only a common ground. The sensor is operated by applying a fixed voltage to its input pin and monitor the current, which is temperature depended.

3. Ordering information

Table 3.Ordering information

Package name	Orderable part number	12NC	Packing description	Min. orderable quantity (pieces)
ACC-1230-6F-3	ART2K0TFEJ	9349 607 63118	TR13; 100-fold; 56 mm; non-dry pack	100
ACC-1230-6F-2	ART2K0TFESJ	9349 606 36118	TR13; 100-fold; 56 mm; non-dry pack	100
ACC-1230-6G-2	ART2K0TFEGJ	9349 606 35118	TR13; 100-fold; 56 mm; non-dry pack	100

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{DS}	drain-source voltage	[1]	-	200	V
V _{GS}	gate-source voltage		-9	+13	V
V _{TS}	temperature sensor voltage		-9	+5.5	V
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature	[2]	-	225	°C

[1] Specified over lifetime at maximum operating temperature.

[2] Continuous use at maximum temperature will affect the reliability, for details refer to the online MTF calculator.

5. Thermal characteristics

Table 5.Thermal characteristics

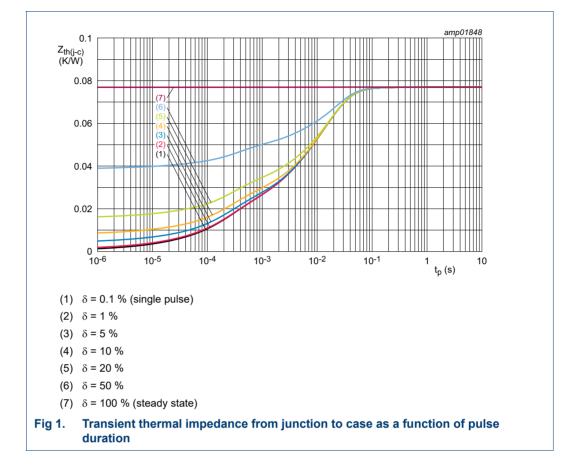
According to standard MIL-STD-883E.

Symbol	Parameter	Conditions	Тур	Unit
R _{th(j-c)}	thermal resistance from junction to case	$T_j = 95 ^{\circ}C$, measured [1][2] under RF condition	0.077	K/W

[1] Refer to application note AN221014 on the Ampleon website.

[2] See Figure 1.

Power LDMOS transistor



6. Characteristics

Table 6. DC characteristics

 T_i = 25 °C; per section unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{(BR)DSS}	drain-source breakdown voltage	V _{GS} = 0 V; I _D = 5.5 mA	203	208	-	V
V _{GS(th)}	gate-source threshold voltage	V _{DS} = 20 V; I _D = 550 mA	1.6	2.1	2.6	V
V _{TS(th)}	temperature sensor threshold voltage	I _{TS} = 0.7 mA	1.75	2.3	2.75	V
I _{DSS}	drain leakage current	V _{GS} = 0 V; V _{DS} = 65 V	-	-	2.8	μA
I _{DSX}	drain cut-off current	V _{GS} = V _{GS(th)} + 3.75 V; V _{DS} = 20 V	-	76	-	A
I _{GSS}	gate leakage current	V _{GS} = 11 V; V _{DS} = 0 V	-	-	280	nA
R _{DS(on)}	drain-source on-state resistance	V _{GS} = V _{GS(th)} + 3.75 V; I _D = 19.25 A	-	0.107	-	Ω

Table 7.	AC	characteristics
		ciluluctoristics

 $T_j = 25$ °C; per section unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
C _{rs}	feedback capacitance	V _{GS} = 0 V; V _{DS} = 65 V; f = 1 MHz	-	1.88	-	pF
C _{iss}	input capacitance	V _{GS} = 0 V; V _{DS} = 65 V; f = 1 MHz	-	598	-	pF
C _{oss}	output capacitance	V _{GS} = 0 V; V _{DS} = 65 V; f = 1 MHz	-	179	-	pF

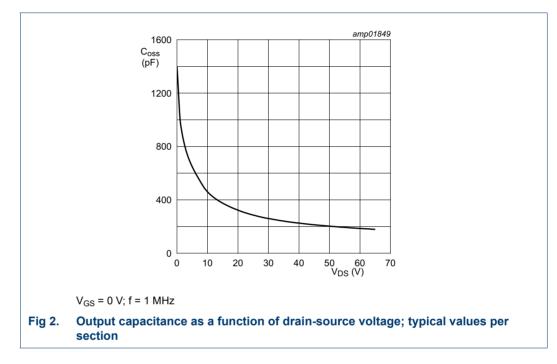


Table 8. RF characteristics

Test signal: pulsed RF; $t_p = 100 \ \mu s$; $\delta = 5 \ \%$; $f = 108 \ MHz$; RF performance at $V_{DS} = 65 \ V$; $I_{Dq} = 50 \ mA$ per section; $T_{case} = 25 \ C$; unless otherwise specified; in a class-AB production test circuit.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
G _p	power gain	P _L = 2000 W	27	29	-	dB
RL _{in}	input return loss	P _L = 2000 W	-	-15	-	dB
η _D	drain efficiency	P _L = 2000 W	68	73	-	%

7. Test information

7.1 Ruggedness in class-AB operation

The ART2K0TFE, ART2K0TFES and ART2K0TFEG are capable of withstanding a load mismatch corresponding to VSWR \geq 65 : 1 through all phases under the following conditions: V_{DS} = 65 V; I_{Dq} = 100 mA per section; P_L = 2000 W pulsed; t_p = 100 µs; δ = 10 %; f = 108 MHz.

7.2 Impedance information

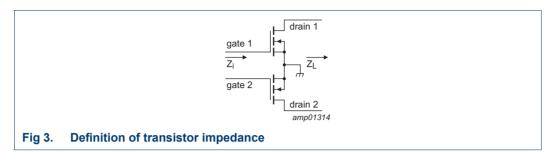
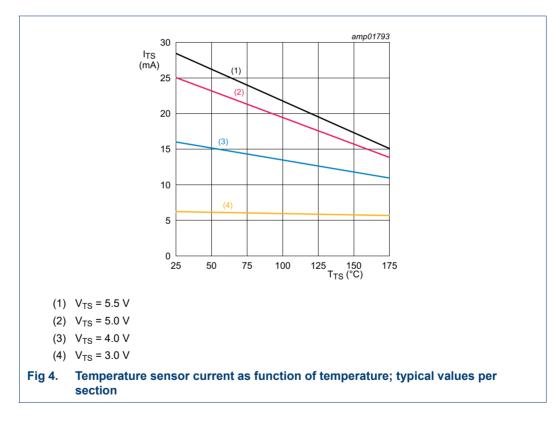


Table 9. Typical push-pull impedance

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Simulated Z_i and Z_L device impedance; impedance info at V_{DS} = 65 V and P_L = 2000 W.
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f	Z _i	ZL
(MHz)	(Ω)	(Ω)
108	2.4 – j8.9	3.9 + j1.0

7.3 Graphical data thermal sensor



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7.4 Test circuit

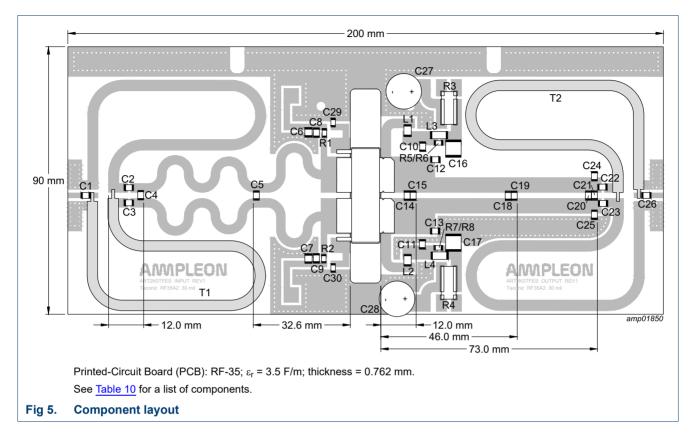


Table 10. List of components

For test circuit see <u>Figure 5</u>.

Component	Description	Value	Remarks
C1, C26	multilayer ceramic chip capacitor	470 pF	1
C2, C3	multilayer ceramic chip capacitor	68 pF [1	1
C4	multilayer ceramic chip capacitor	43 pF [1	1
C5	multilayer ceramic chip capacitor	240 pF	1
C6, C7	multilayer ceramic chip capacitor	4.7 μF, 50 V	Murata: GRM32ER71H475KA88L
C8, C9, C10, C11	multilayer ceramic chip capacitor	820 pF	1
C12, C13	multilayer ceramic chip capacitor	180 pF	1
C14, C15	multilayer ceramic chip capacitor	39 pF [1	1
C16, C17	multilayer ceramic chip capacitor	4.7 μF, 100 V	TDK: C5750X7R2A475KT/A
C18, C19	multilayer ceramic chip capacitor	56 pF [1	1
C20, C21	multilayer ceramic chip capacitor	51 pF [1	1
C22, C23	multilayer ceramic chip capacitor	120 pF	1
C24, C25	multilayer ceramic chip capacitor	20 pF	1
C27, C28	electrolytic capacitor	2200 μF, 100 V	
C29, C30	multilayer ceramic chip capacitor	1 μF, 25 V	SMD 1206
L1, L2	square air core inductor	47 nH	Coilcraft: 1515SQ-47N
L3, L4	square air core inductor	82 nH	Coilcraft: 1515SQ-82N

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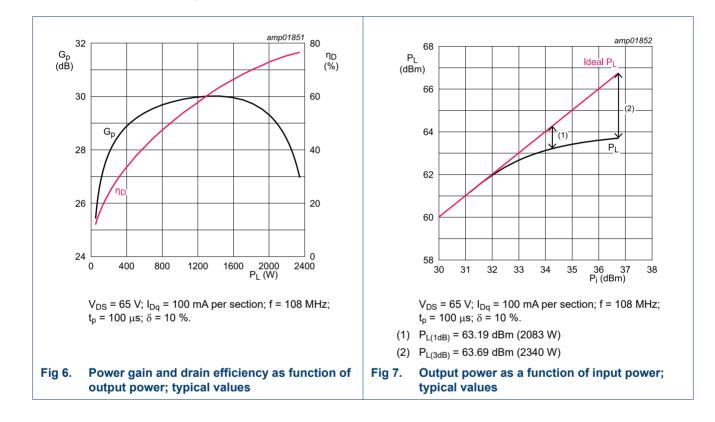
Table 10. List of components ... continued For test circuit see Figure 5.

oomponent	Description	Value	Kennarka		
R1, R2	chip resistor	4.7 kΩ	SMD 1206		
R3, R4	chip resistor	0.01 Ω	FC4L110R010FER		
R5, R6, R7, R8	chip resistor	9.1 Ω	SMD 1206		
T1, T2 semi rigid coax 50 Ω, 160 mm EZ141-AL-TP/M17					
[1] American Technical Ceramics type 100B or capacitor of same quality.					

Valuo

Component Description

[1] e 100B or cap type

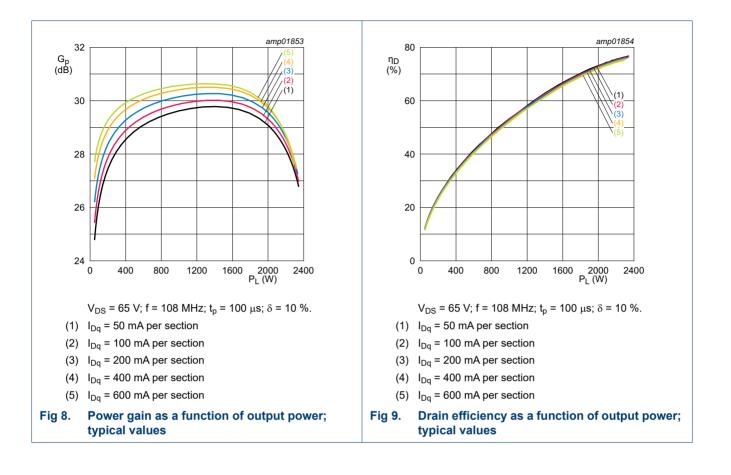


7.5 Graphical data

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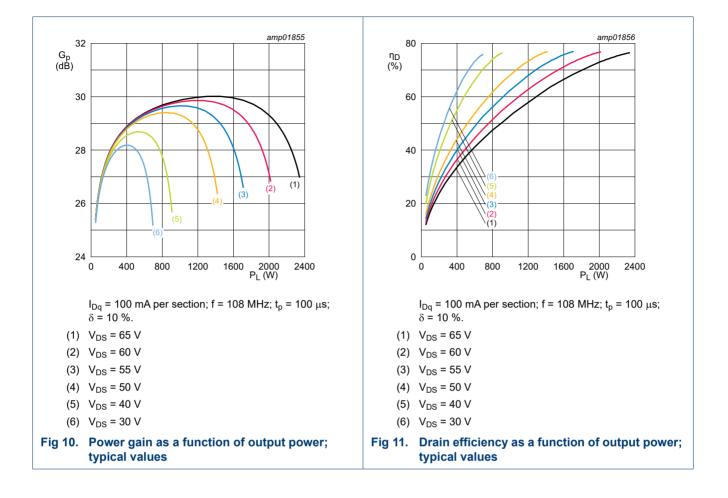
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ART2K0TFE(S)(G)

Power LDMOS transistor





Power LDMOS transistor

8. Package outline

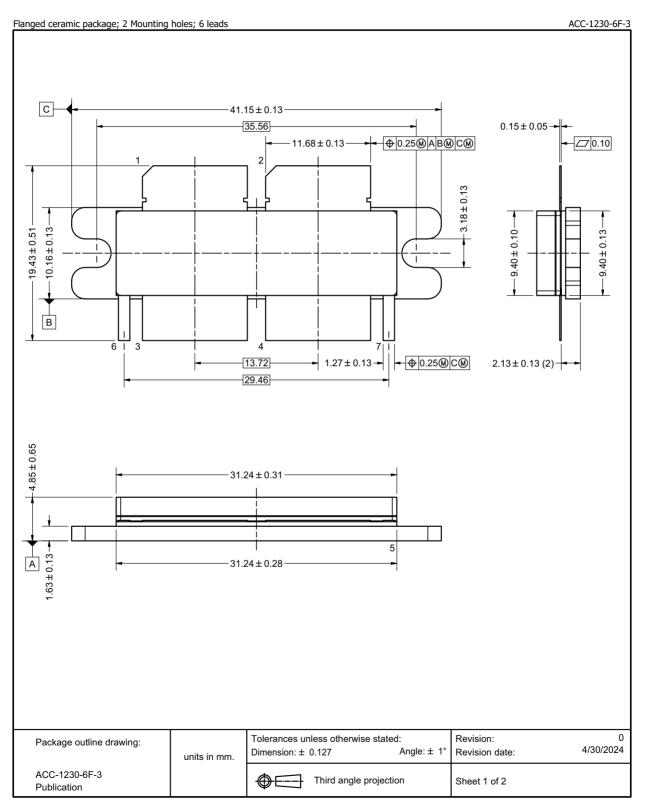


Fig 12. Package outline ACC-1230-6F-3 (sheet 1 of 2)



ACC-1230-6F-3

Items Description (1) Millimeter dimensions are takinod from the original inch dimensions. (2) Dimension is measured 0.030 inch (0.76 mm) from the body. (3) Recommended screw pitch dimension of 1.48 inch (37.52 mm) based on M3 screw.			Drawing Notes	
(1) Millimeter dimensions are derived from the original inch dimensions. (2) Dimension is measured 0.30 mol (0.76 mm) from the body. (3) Recommended screw pitch dimension of 1.48 inch (37.52 mm) based on M3 screw. (3) Recommended screw pitch dimension of 1.48 inch (37.52 mm) based on M3 screw. Package outline drawing: units in mm. Unit in mm. Tolerances unless otherwise stated: Dimension: ± 0.127 Revision: Angle. ± 1 Revision: 4/30/202	Items		Description	
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Package outline drawing. Dimension: ± 0.127 Angle: $\pm 1^{\circ}$ Revision date: $4/30/202$ Acco 1000 cF 0				
Publication Third angle projection Sheet 2 of 2	ACC-1230-6F-3	units in mm.		

Fig 13. Package outline ACC-1230-6F-3 (sheet 2 of 2)

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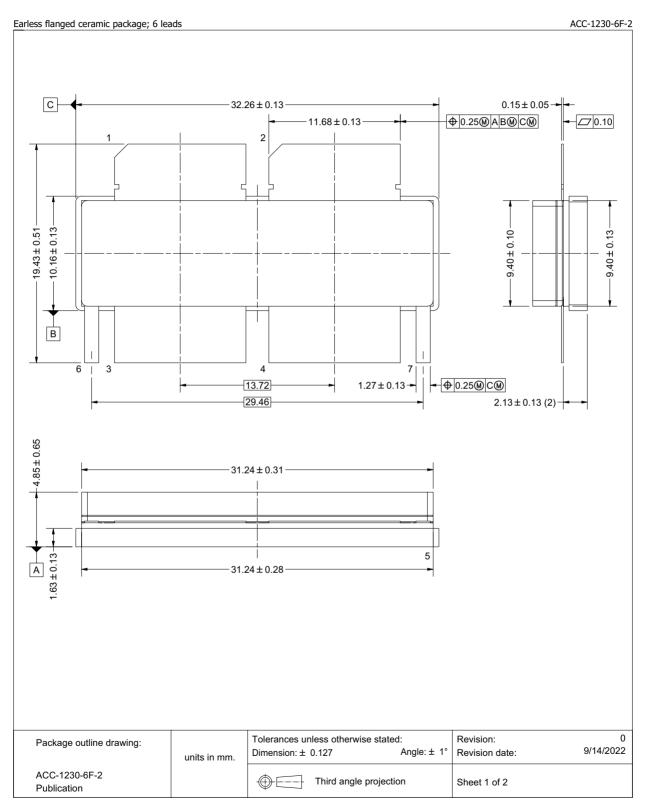


Fig 14. Package outline ACC-1230-6F-2 (sheet 1 of 2)

ART2K0TFE_2K0TFES_2K0TFEG



ACC-1230-6F-2

		Drawing Notes]		
Items		Description			
	Millimeter dimensions are derived from the original inch dimensions.				
(1) (2)	Dimension is measured 0.030 inch (0.76) from the body.				
Package outline drawing:		Tolerances unless otherwise stated:	Revision: 0		
ACC-1230-6F-2	units in mm.	Dimension: ± 0.127 Angle: ± 1°	Revision date: 9/14/2022		
Publication		- Third angle projection	Sheet 2 of 2		

Fig 15. Package outline ACC-1230-6F-2 (sheet 2 of 2)

ART2K0TFE(S)(G)
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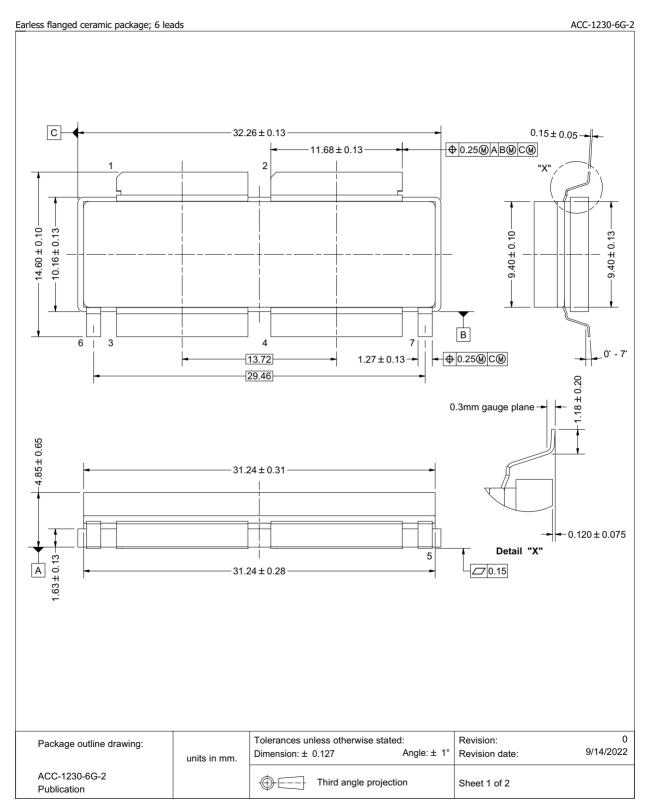


Fig 16. Package outline ACC-1230-6G-2 (sheet 1 of 2)

ART2K0TFE_2K0TFES_2K0TFEG



ACC-1230-6G-2

		Drawing Notes		
Items (1)		Description		
(1)	Millim	neter dimensions are derived from the original inc	ch dimensions.	
Package outline drawing:		Tolerances unless otherwise stated:	Revision:	
Package outline drawing:			Revision: Revision date:	9/14/20
Package outline drawing:	units in mm.	Tolerances unless otherwise stated: Dimension: ± 0.127 Angle: ± 1°	Revision: Revision date:	9/14/20
Package outline drawing: ACC-1230-6G-2	units in mm.			9/14/20

Fig 17. Package outline ACC-1230-6G-2 (sheet 2 of 2)

9. Handling information

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the ANSI/ESD S20.20, IEC/ST 61340-5, JESD625-A or equivalent standards.

Table 11.ESD sensitivity

ESD model	Class
Charged Device Model (CDM); According to ANSI/ESDA/JEDEC standard JS-002	C2A
Human Body Model (HBM); According to ANSI/ESDA/JEDEC standard JS-001	2

10. Abbreviations

Acronym	Description
CW	Continuous Wave
ESD	ElectroStatic Discharge
FM	Frequency Modulation
FET	Field-Effect Transistor
ISM	Industrial, Scientific and Medical
LDMOS	Laterally Diffused Metal-Oxide Semiconductor
MRI	Magnetic Resonance Imaging
MTF	Median Time to Failure
RoHS	Restriction of Hazardous Substances
SMD	Surface Mounted Device
UHF	Ultra High Frequency
VHF	Very High Frequency
VSWR	Voltage Standing Wave Ratio

11. Revision history

Table 13. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
ART2K0TFE_2K0TFES_2K0TFEG v.3	20250212	Product data sheet	-	ART2K0TFES_ART2K0TF EG v.2
Modifications:	Table 4 on page	e 3: updated table		
ART2K0TFE_2K0TFES_2K0TFEG v.2	20240731	Product data sheet	-	ART2K0TFES_ART2K0TF EG v.1
ART2K0TFES_ART2K0TFEG v.1	20230707	Product data sheet	-	-

12. Legal information

12.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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